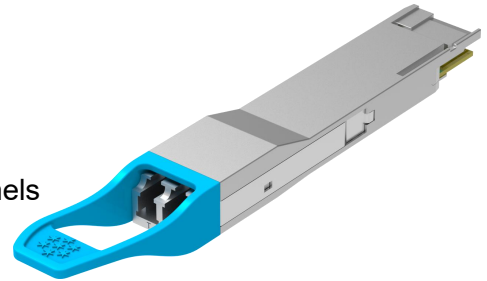


## 200G QSFP-DD LR8 Optical Transceiver Module

### GQD-SPO201-L28C

#### Features

- ◆ 8 channels full-duplex transceiver modules
- ◆ Transmission data rate up to 26Gbps per channel
- ◆ 8 x 26Gb/s DFB-based LAN-WDM Cooling transmitter
- ◆ 8 channels PIN ROSA
- ◆ Internal CDR circuits on both receiver and transmitter channels
- ◆ Support CDR bypass
- ◆ Low power consumption <7.5W
- ◆ Hot Pluggable QSFP DD form factor and Compliant with CMIS
- ◆ Up to 20km reach for G.652 SMF
- ◆ Duplex LC receptacles
- ◆ Built-in digital diagnostic functions
- ◆ Operating case temperature 0°C to +70°C
- ◆ 3.3V power supply voltage
- ◆ RoHS 6 compliant (lead free)



#### Applications

- ◆ 200G LR8 Ethernet

#### Description

The Gigalight Technologies GQD-SPO201-L28C is an Eight-Channel, Pluggable, Fiber-Optic QSFP DD LR8 for 200G Ethernet applications. This transceiver is a high performance module for data communication and interconnect applications. It integrates eight data lanes in each direction with 206.25Gbps bandwidth. Each lane can operate at 25.78125Gbps up to 20km over G.652 SMF. These modules are designed to operate over single-mode fiber systems using 8 LAN-WDM wavelengths. The electrical interface uses a 76 contact edge type connector. The optical interface uses duplex LC connector. This module incorporates Gigalight Technologies proven circuit and Optical technology to provide reliable long life, high performance, and consistent service.

## 200G QSFP DD LR8 CIRCUIT STRUCTURE

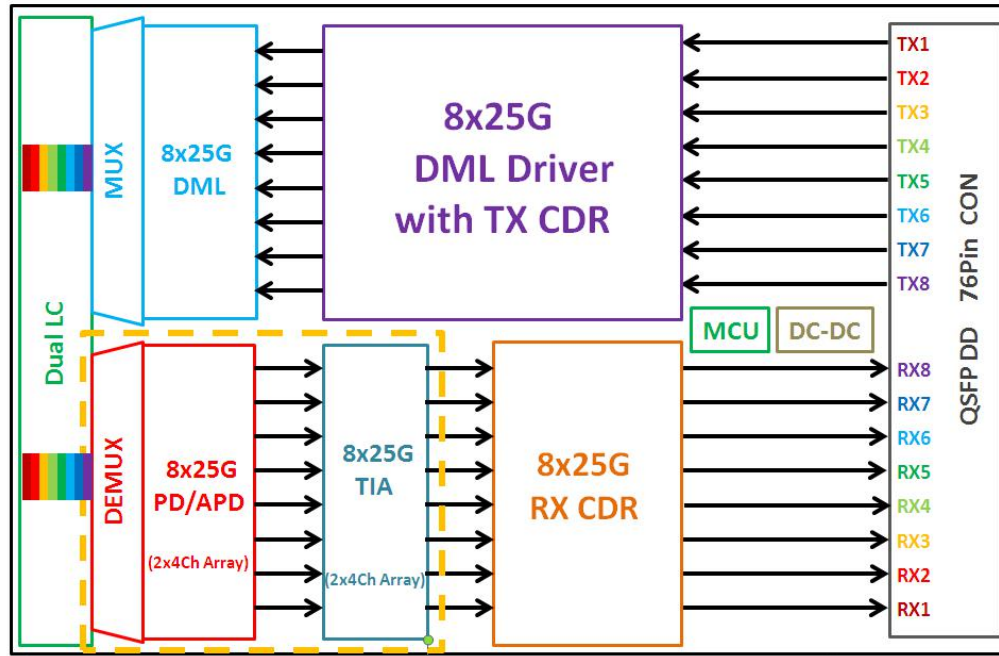


Figure1. Module Block Diagram

### Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>cc</sub>	-0.3	3.6	V
Input Voltage	V <sub>in</sub>	-0.3	V <sub>cc</sub> +0.3	V
Storage Temperature	T <sub>st</sub>	-20	85	°C
Case Operating Temperature	T <sub>op</sub>	0	70	°C
Humidity(non-condensing)	R <sub>h</sub>	5	95	%

### Recommended Operating Conditions

Parameter	Symbol	Min	Typical	Max	Unit
Supply Voltage	V <sub>cc</sub>	3.13	3.3	3.47	V
OperatingCase Temperature	T <sub>c</sub>	0		70	°C
Data Rate Per Lane	f <sub>d</sub>		25.78125		Gbps
Humidity	R <sub>h</sub>	5		85	%
Power Dissipation	P <sub>m</sub>			7.5	W
Fiber Bend Radius	R <sub>b</sub>	0.002		20	km

## Electrical Specifications

Parameter	Symbol	Min	Typical	Max	Unit
Differential Input Impedance	$Z_{in}$	90	100	110	ohm
Differential Output Impedance	$Z_{out}$	90	100	110	ohm
Differential Input Voltage Amplitude <sup>1</sup>	$\Delta V_{in}$	190		700	mVp-p
Differential Output Voltage Amplitude <sup>2</sup>	$\Delta V_{out}$	300		850	mVp-p
Input Logic Level High	$V_{IH}$	2.0		$V_{cc}$	V
Input Logic Level Low	$V_{IL}$	0		0.8	V
Output Logic Level High	$V_{OH}$	$V_{cc}-0.5$		$V_{cc}$	V
Output Logic Level Low	$V_{OL}$	0		0.4	V

### Note:

1. Differential input voltage amplitude is measured between TxnP and TxnN.
2. Differential output voltage amplitude is measured between RxnP and RxnN.

## Optical Characteristics

**Table 3 - Optical Characteristics**

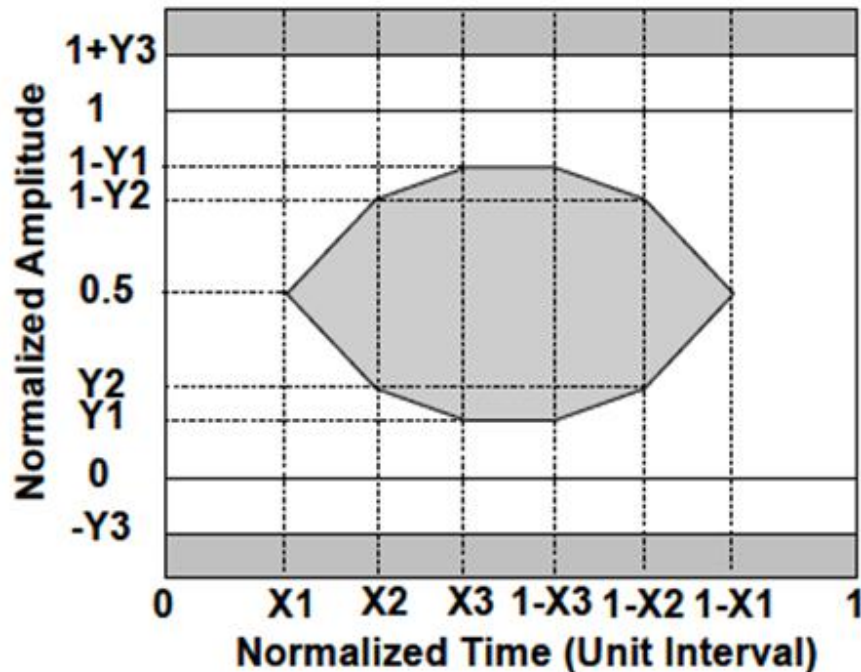
100GBASE-LR4						
Parameter	Symbol	Min	Typical	Max	Unit	Notes
Lane Wavelength	L0	1272.55	1273.54	1274.54	nm	
	L1	1276.89	1277.89	1278.89	nm	
	L2	1281.25	1282.26	1283.27	nm	
	L3	1285.65	1286.66	1287.68	nm	
	L4	1294.53	1295.56	1296.59	nm	
	L5	1299.02	1300.05	1301.09	nm	
	L6	1303.54	1304.58	1305.63	nm	
	L7	1308.09	1309.14	1310.19	nm	
Transmitter						
SMSR	SMSR	30			dB	
Total Average Launch Power	$P_T$			10.5	dBm	
Average Launch Power, each Lane	$P_{AVG}$	-4.3		4.5	dBm	
OMA, each Lane	$P_{OMA}$	-1.3		4.5	dBm	1
Difference in Launch Power	$P_{tx,diff}$			5	dB	

Launch Power in OMA		-2.3			dBm	
TDP, each Lane	TDP			2.2	dB	
Extinction Ratio	ER	4			dB	
RIN <sub>20</sub> OMA	RIN			-130	dB/H	
Optical Return Loss	TOL			20	dB	
Transmitter Reflectance	R <sub>T</sub>			-12	dB	
Eye Mask coordinates: X1, X2, X3, Y1, Y2, Y3		{0.25, 0.4, 0.45, 0.25, 0.28, 0.4}				2
Average Launch Power OFF	Poff			-30	dBm	
<b>Receiver</b>						
Damage Threshold, each Lane	TH <sub>d</sub>	5.5			dBm	3
Total Average Receive				10.5	dBm	
Average Receive Power, each Lane		-10.6		4.5	dBm	
Receive Power (OMA), each Lane				4.5	dBm	
Receiver Sensitivity (OMA), each Lane	SEN			-8.6	dBm	
Stressed Receiver Sensitivity (OMA), each Lane				-6.8	dBm	4
Difference in Receive Power between any Two Lanes (OMA)	Prx,diff			5.5	dB	
LOS Assert	LOSA		-18		dBm	
LOS Deassert	LOSD		-15		dBm	
LOS Hysteresis	LOSH	0.5			dB	
Receiver Electrical 3 dB upper Cutoff Frequency, each Lane	F <sub>c</sub>			31	GHz	
<b>Conditions of Stress Receiver Sensitivity Test (Note 5)</b>						

Vertical Eye Closure Penalty, each Lane			1.8		dB	5
Stressed Eye J2 Jitter, each Lane			0.3		UI	
Stressed Eye J9 Jitter, each Lane			0.47		UI	

**Note:**

1. Even if the TDP < 1 dB, the OMA min must exceed the minimum value specified here.
2. See Figure 4 below.
3. The receiver shall be able to tolerate, without damage, continuous exposure to a modulated optical input signal having this power level on one lane. The receiver does not have to operate correctly at this input power.
4. Measured with conformance test signal at receiver input for BER =  $1 \times 10^{-12}$ .
5. Vertical eye closure penalty and stressed eye jitter are test conditions for measuring stressed receiver sensitivity. They are not characteristics of the receiver.



## Pin Description

Pad	Logic	Symbol	Description	Plug Sequence <sup>4</sup>	Notes
1		GND	Ground	1B	1
2	CML-I	Tx2n	Transmitter Inverted Data Input	3B	
3	CML-I	Tx2p	Transmitter Non-Inverted Data Input	3B	
4		GND	Ground	1B	1
5	CML-I	Tx4n	Transmitter Inverted Data Input	3B	
6	CML-I	Tx4p	Transmitter Non-Inverted Data Input	3B	
7		GND	Ground	1B	1
8	LVTTL-I	ModSelL	Module Select	3B	
9	LVTTL-I	ResetL	Module Reset	3B	
10		VccRx	+3.3V Power Supply Receiver	2B	2
11	LVCNOS-I/O	SCL	2-wire serial interface clock	3B	
12	LVCNOS-I/O	SDA	2-wire serial interface data	3B	
13		GND	Ground	1B	1
14	CML-O	Rx3p	Receiver Non-Inverted Data Output	3B	
15	CML-O	Rx3n	Receiver Inverted Data Output	3B	
16		GND	Ground	1B	1
17	CML-O	Rx1p	Receiver Non-Inverted Data Output	3B	
18	CML-O	Rx1n	Receiver Inverted Data Output	3B	
19		GND	Ground	1B	1
20		GND	Ground	1B	1
21	CML-O	Rx2n	Receiver Inverted Data Output	3B	
22	CML-O	Rx2p	Receiver Non-Inverted Data Output	3B	
23		GND	Ground	1B	1
24	CML-O	Rx4n	Receiver Inverted Data Output	3B	
25	CML-O	Rx4p	Receiver Non-Inverted Data Output	3B	
26		GND	Ground	1B	1
27	LVTTL-O	ModPrsL	Module Present	3B	
28	LVTTL-O	IntL	Interrupt	3B	
29		VccTx	+3.3V Power supply transmitter	2B	2
30		Vcc1	+3.3V Power supply	2B	2
31	LVTTL-I	LPMode	Low Power mode;	3B	
32		GND	Ground	1B	1
33	CML-I	Tx3p	Transmitter Non-Inverted Data Input	3B	
34	CML-I	Tx3n	Transmitter Inverted Data Input	3B	
35		GND	Ground	1B	1
36	CML-I	Tx1p	Transmitter Non-Inverted Data Input	3B	
37	CML-I	Tx1n	Transmitter Inverted Data Input	3B	
38		GND	Ground	1B	1

Pad	Logic	Symbol	Description	Plug Sequence <sup>4</sup>	Notes
39		GND	Ground	1A	1
40	CML-I	Tx6n	Transmitter Inverted Data Input	3A	
41	CML-I	Tx6p	Transmitter Non-Inverted Data Input	3A	
42		GND	Ground	1A	1
43	CML-I	Tx8n	Transmitter Inverted Data Input	3A	
44	CML-I	Tx8p	Transmitter Non-Inverted Data Input	3A	
45		GND	Ground	1A	1
46		Reserved	For future use	3A	3
47		VS1	Module Vendor Specific 1	3A	3
48		VccRx1	3.3V Power Supply	2A	2
49		VS2	Module Vendor Specific 2	3A	3
50		VS3	Module Vendor Specific 3	3A	3
51		GND	Ground	1A	1
52	CML-O	Rx7p	Receiver Non-Inverted Data Output	3A	
53	CML-O	Rx7n	Receiver Inverted Data Output	3A	
54		GND	Ground	1A	1
55	CML-O	Rx5p	Receiver Non-Inverted Data Output	3A	
56	CML-O	Rx5n	Receiver Inverted Data Output	3A	
57		GND	Ground	1A	1
58		GND	Ground	1A	1
59	CML-O	Rx6n	Receiver Inverted Data Output	3A	
60	CML-O	Rx6p	Receiver Non-Inverted Data Output	3A	
61		GND	Ground	1A	1
62	CML-O	Rx8n	Receiver Inverted Data Output	3A	
63	CML-O	Rx8p	Receiver Non-Inverted Data Output	3A	
64		GND	Ground	1A	1
65		NC	No Connect	3A	3
66		Reserved	For future use	3A	3
67		VccTx1	3.3V Power Supply	2A	2
68		Vcc2	3.3V Power Supply	2A	2
69	LVTTL-I	ePPS	Precision Time Protocol (PTP) reference clock input	3A	3
70		GND	Ground	1A	1
71	CML-I	Tx7p	Transmitter Non-Inverted Data Input	3A	
72	CML-I	Tx7n	Transmitter Inverted Data Input	3A	
73		GND	Ground	1A	1
74	CML-I	Tx5p	Transmitter Non-Inverted Data Input	3A	
75	CML-I	Tx5n	Transmitter Inverted Data Input	3A	
76		GND	Ground	1A	1

Note 1: QSFP-DD uses common ground (GND) for all signals and supply (power). All are common within the QSFP-DD module and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal-common ground plane.

Note 2: VccRx, VccRx1, Vcc1, Vcc2, VccTx and VccTx1 shall be applied concurrently. Requirements defined for the host side of the Host Card Edge Connector are listed in Table 7. VccRx, VccRx1, Vcc1, Vcc2, VccTx and VccTx1 may be internally connected within the module in any combination. The connector Vcc pins are each rated for a maximum current of 1000 mA.

Note 3: All Vendor Specific, Reserved, No Connect and ePPS (if not used) pins may be terminated with 50 Ohms to ground on the host. Pad 65 (No Connect) shall be left unconnected within the module. Vendor specific and Reserved pads shall have an impedance to GND that is greater than 10 kOhms and less than 100 pF.

Note 4: Plug Sequence specifies the mating sequence of the host connector and module. The sequence is 1A, 2A, 3A, 1B, 2B, 3B. (see Figure 2 for pad locations) Contact sequence A will make, then break contact with additional QSFP-DD pads. Sequence 1A,1B will then occur simultaneously, followed by 2A,2B, followed by 3A,3B.

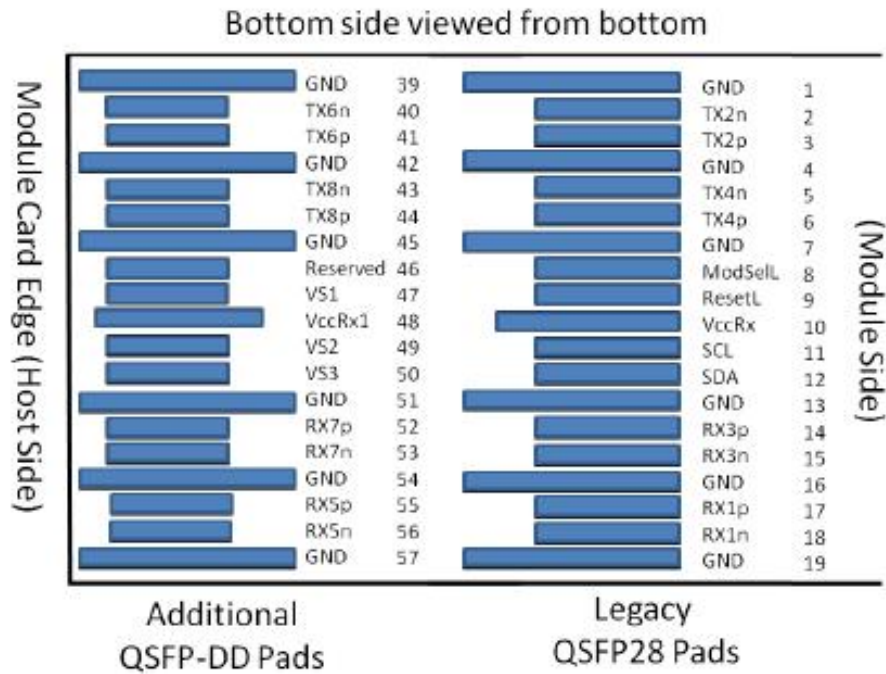
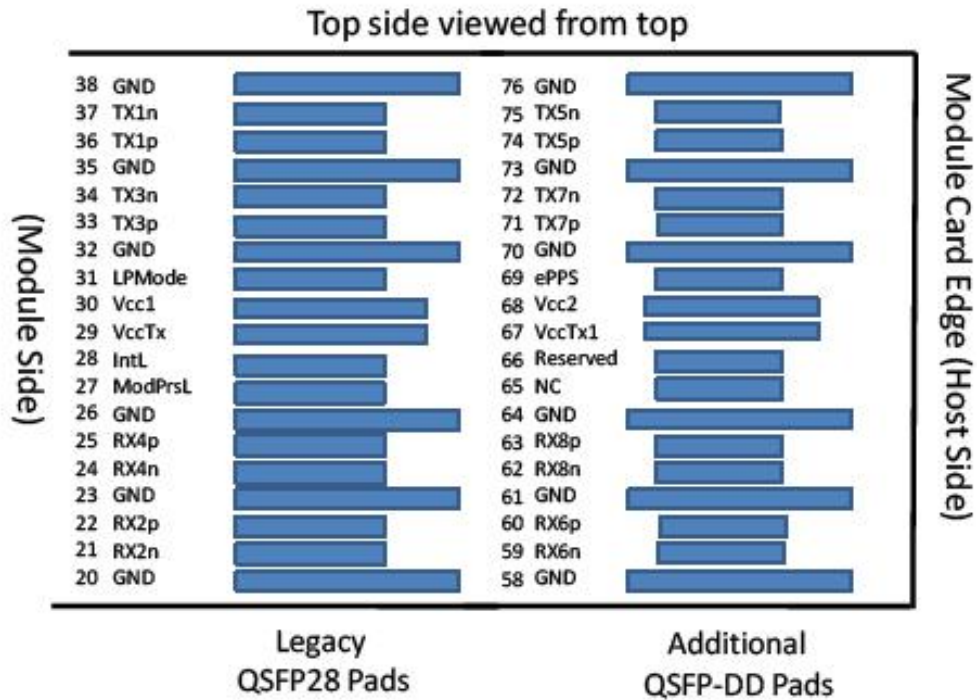


Figure2. Electrical Pin-out Details



### **ModSelL Pin**

The ModSelL is an input signal that must be pulled to Vcc in the QSFP-DD module. When held low by the host, the module responds to 2-wire serial communication commands. The ModSelL allows the use of multiple QSFP-DD modules on a single 2-wire interface bus. When ModSelL is “High”, the module shall not respond to or acknowledge any 2-wire interface communication from the host.

In order to avoid conflicts, the host system shall not attempt 2-wire interface communications within the ModSelL de-assert time after any QSFP-DD modules are deselected. Similarly, the host must wait at least for the period of the ModSelL assert time before communicating with the newly selected module. The assertion and de-asserting periods of different modules may overlap as long as the above timing requirements are met.

### **ResetL Pin**

The ResetL signal shall be pulled to Vcc in the module. A low level on the ResetL signal for longer than the minimum pulse length ( $t_{\text{Reset\_init}}$ ) (See Table 13 ) initiates a complete module reset, returning all user module settings to their default state.

### **LPMODE Pin**

LPMODE is an input signal. The LPMODE signal shall be pulled up to Vcc in the QSFP-DD module (see Table 2). LPMODE is used in the control of the module power mode.

See CMIS Section 6.3.1.3.

### **ModPrsL Pin**

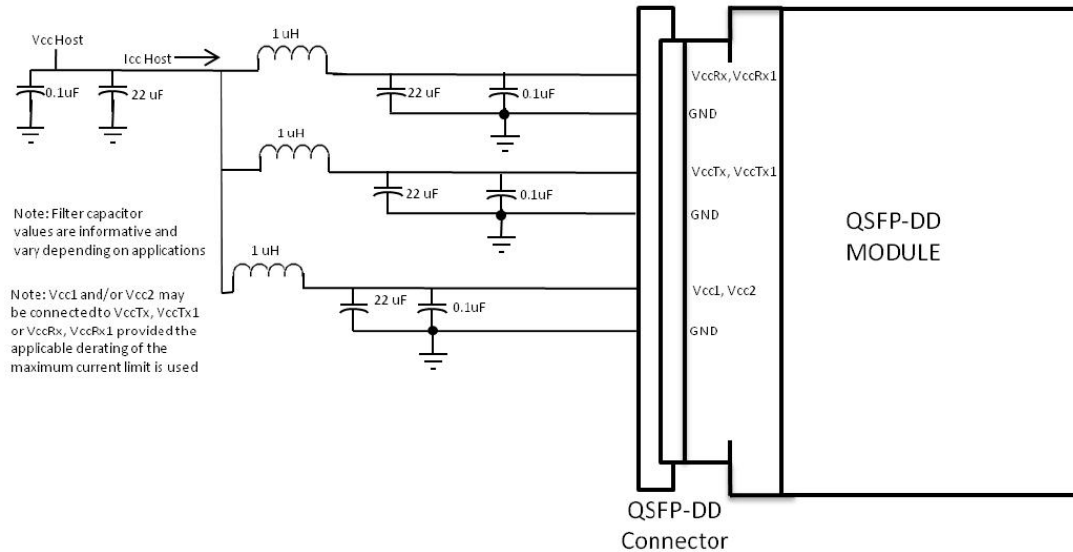
ModPrsL must be pulled up to Vcc Host on the host board and grounded in the module. The ModPrsL is asserted “Low” when the module is inserted and deasserted “High” when the module is physically absent from the host connector.

### **IntL Pin**

IntL is an output signal. The IntL signal is an open collector output and must be pulled to Vcc Host on the host board. When the IntL signal is asserted Low it indicates a change in module state, a possible module operational fault or a status critical to the host system. The host identifies the source of the interrupt using the 2-wire serial interface. The IntL signal is deasserted “High” after all set interrupt flags are read.

## Power Supply Filtering

The host board should use the power supply filtering shown in Figure3.



**Figure3. Host Board Power Supply Filtering**

## DIAGNOSTIC MONITORING INTERFACE

Digital diagnostics monitoring function is available on all Gigalight QSFP DD products. A 2-wire serial interface provides user to contact with module.

This subsection defines the Memory Map for a CMIS Module used for serial ID, digital 3 monitoring and certain control functions. The interface is mandatory for all CMIS 4 devices. The interface has been designed largely after the QSFP memory map. The memory 5 map has been changed in order to accommodate 8 electrical lanes and limit the required 6 memory space. The single address approach is used as found in QSFP. Paging is used in 7 order to enable time critical interactions between host and module.

The structure of the memory is shown in Figure 5 . The memory space is arranged into a 10 lower, single page, address space of 128 bytes and multiple upper address space pages. 11 This structure supports a flat 256 byte memory for passive copper cables and permits 12 timely access to addresses in the lower page, e.g. Flags and Monitors. Less time critical 13 entries, e.g. serial ID information and threshold settings, are available with the Page 14 Select function. The structure also provides address expansion by adding additional upper 15 pages as needed. Upper pages 00-02 all contain static,

non-volatile advertising 16 registers. Upper page 01 provides revision codes and advertising registers that indicate 17 the capabilities of the module. Upper page 02 provides thresholds for monitored 18 functions. Upper page 03 provides a user read/write space. The lower page and upper page 19 00 are required for passive copper cables and are always implemented. In addition, upper 20 pages 1, 2 and bank 0 pages 10h and 11h are required for active modules. See CMIS Document Table 40 for 21 details regarding the implementation of optional upper pages and the bank pages. Bank 22 pages are provided to provide the ability to support modules with more than 8 lanes. Bank 23 0 provides lane-specific registers for the lower 8 lanes. Each additional bank provides 24 support for an additional 8 lanes. Reserved bytes are for future use and shall not be 25 used and shall be set to 0. Other organizations shall contact the managing organization 26 or the editor of this document to request allocations of registers. The use of custom 27 bytes is not restricted and may be vendor defined. The use of registers defined as custom 28 may be subject to additional agreements between module users and vendors.

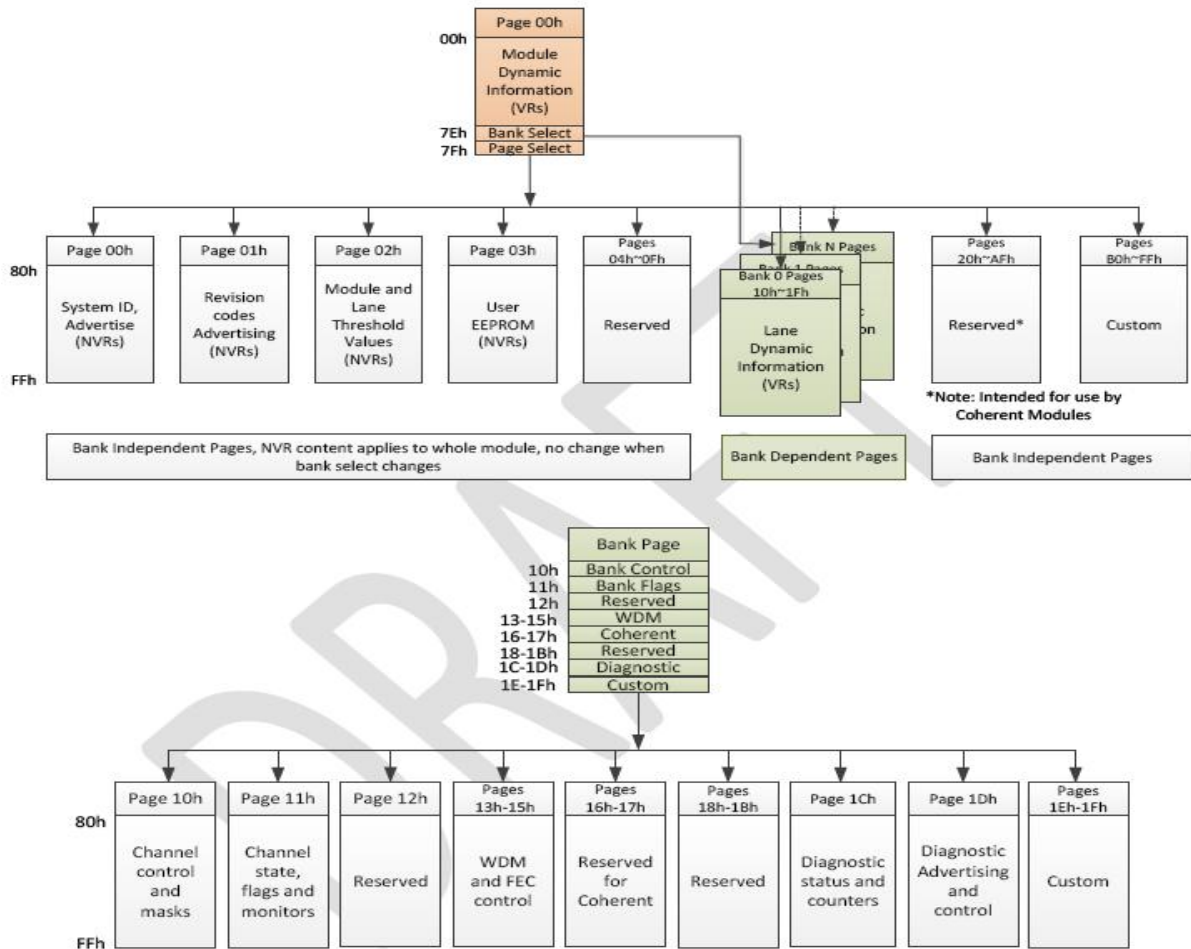
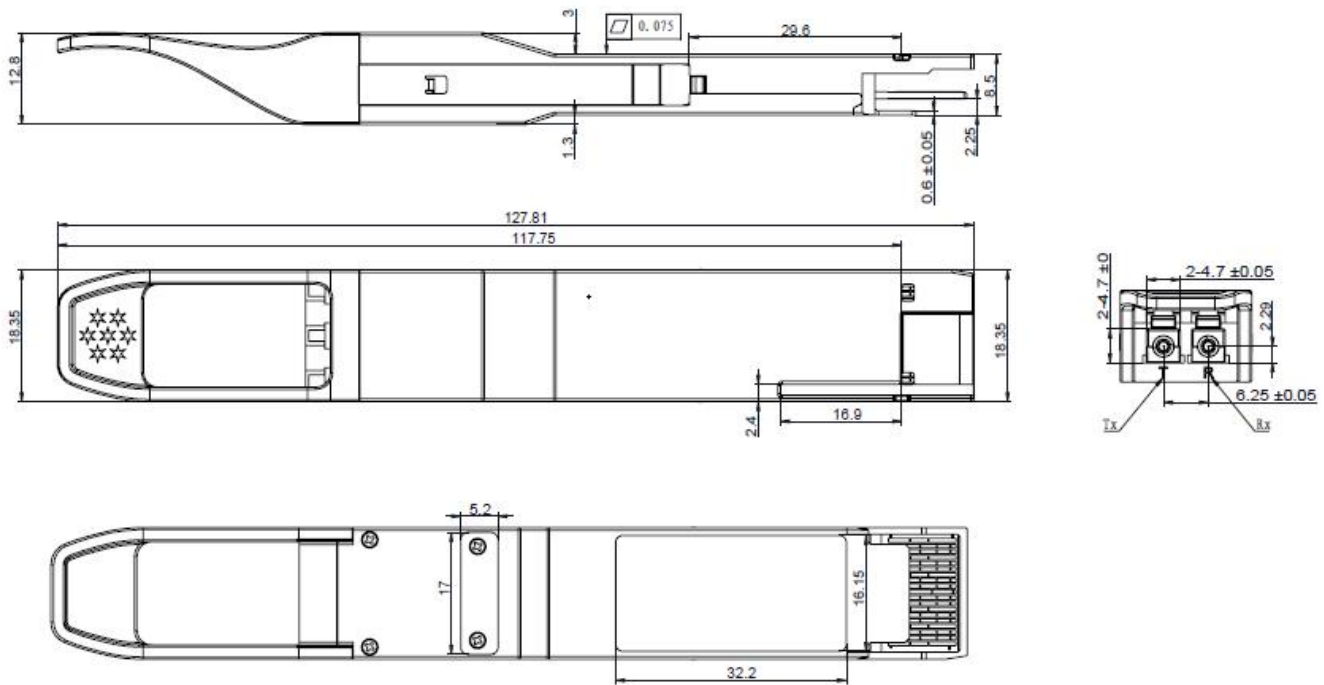


Figure4. QSFP DD Memory Map

## Mechanical Dimensions



**Figure5. Mechanical Specifications**

## Regulatory Compliance

Gigalight GQD-SPO201-L28C transceivers are Class 1 Laser Products. They are certified per the following standards:

Feature	Standard
Laser Safety	IEC 60825-1:2014 (Third Edition)
Environmental protection	2011/65/EU
CE EMC	EN55032: 2015 EN55024: 2010+A1: 2015 EN61000-3-2:2014 EN61000-3-3:2013
FCC	FCC Part 15, Subpart B; ANSI C63.4-2014
Product Safety	EN/UL 60950-1, 2nd Edition, 2014-10-14

## References

1. QSFP DD MAS Rev5.0
2. CMIS V4.0
3. OIF CEI-528G-VSR

## CAUTION:

Use of controls or adjustment or performance of procedures other than those specified herein may result in hazardous radiation exposure.

## Ordering information

Part Number	Product Description
GQD-SPO201-L28C	200G QSFP-DD LR8, LWDM8, 20km, SMF, Dual LC

## Important Notice

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## Revision History

Revision	Date	Description
V0	Sep 14, 2020	Advance Release.